

## Low Sensitivity Micropower Omnipolar Hall-effect Switch

### Features

- Low sensitivity omnipolar operation.
- Micropower operation:  
Type 0.8 $\mu$ A(average :VDD=1.8V)
- Onboard voltage regulator for 1.6V to 5.5V range.
- Magnetic threshold:Bop= $\pm$ 60Gs, Brp= $\pm$ 50Gs
- Industry-leading ultra-low power consumption.
- Wide operating temperature range:  
-40°C to 85°C.
- WBDNF 1.6mm $\times$ 1.2mm $\times$ 0.37mm-4L package

### Applications

- Smartphone.
- Notebook computer.
- Handheld gaming consoles.
- Bluetooth headset.
- DV.
- Contact-less switch, Level, proximity and position switches in consumer products.

### General Description

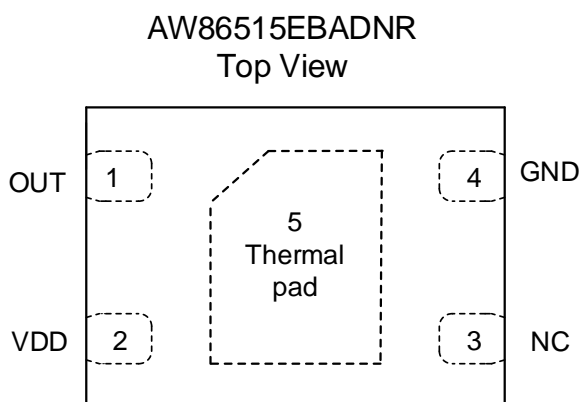
The AW86515 Series device is an ultra-low-power digital-switch Hall effect sensor, designed for the most compact and battery-sensitive systems. The device is offered in multiple sampling rates, output drivers, and packages to accommodate various applications. The supply range of AW86515 series is 1.6V to 5.5V to support portable equipment. To minimize PCB space, the AW86515 series have the ultra-small package: WBDNF 1.6mm $\times$ 1.2mm $\times$ 0.37mm -4L.

When the magnetic field strength is greater than Bop, then the device output is pulled low; When the magnetic field strength is less than Brp, then the device output is pulled high; When the magnetic field strength is between Bop and Brp, then the device output remains in the previous state.

### Typical Application Circuit



## Pin Configuration And Top Mark



AW86515EBADNR Marking  
Top View

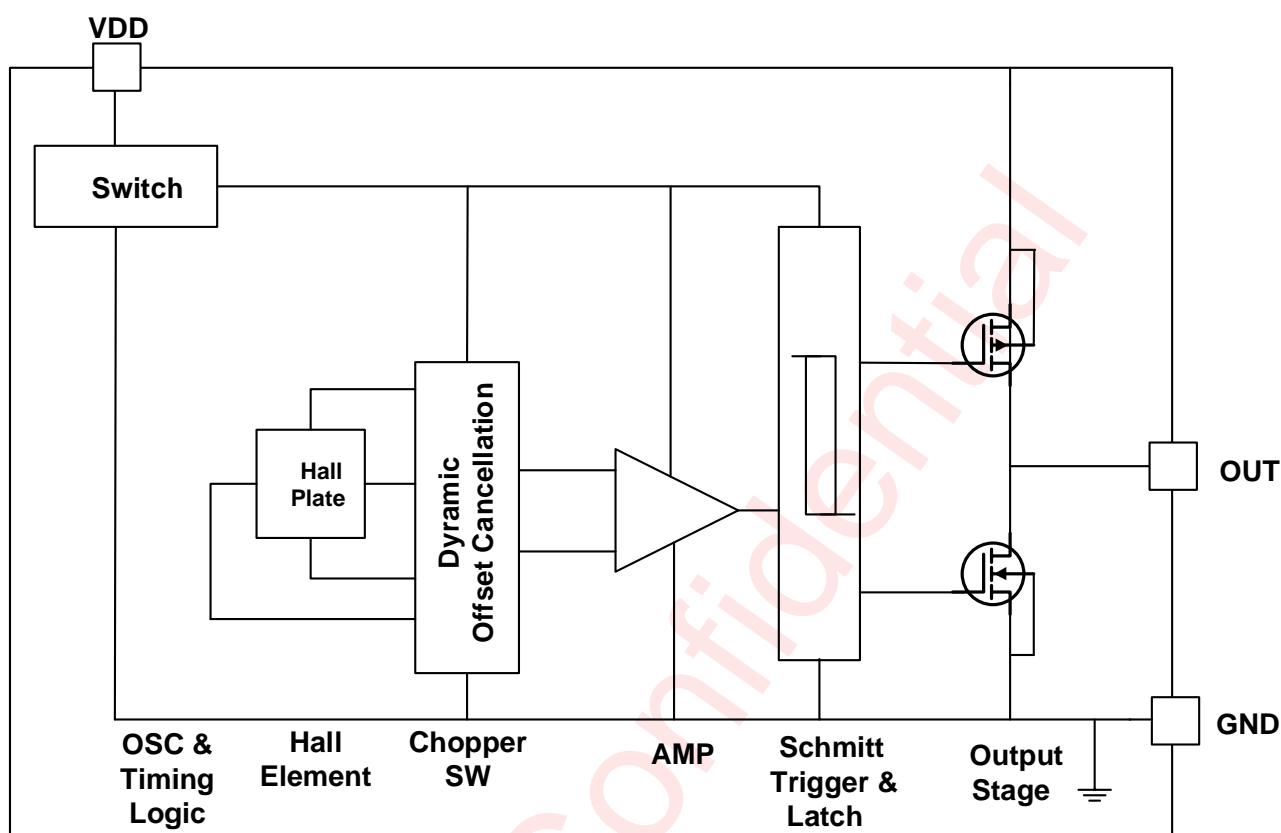


VNxD - AW86515EBADNR  
XXXX - Production Tracing Code

## Pin Definition

No.	NAME	DESCRIPTION
1	OUT	Omnipolar output that responds to north and south magnetic
2	VDD	Power Supply
3	NC	No Connection
4	GND	Ground
5	Thermal pad	No Connection

## Functional Block Diagram

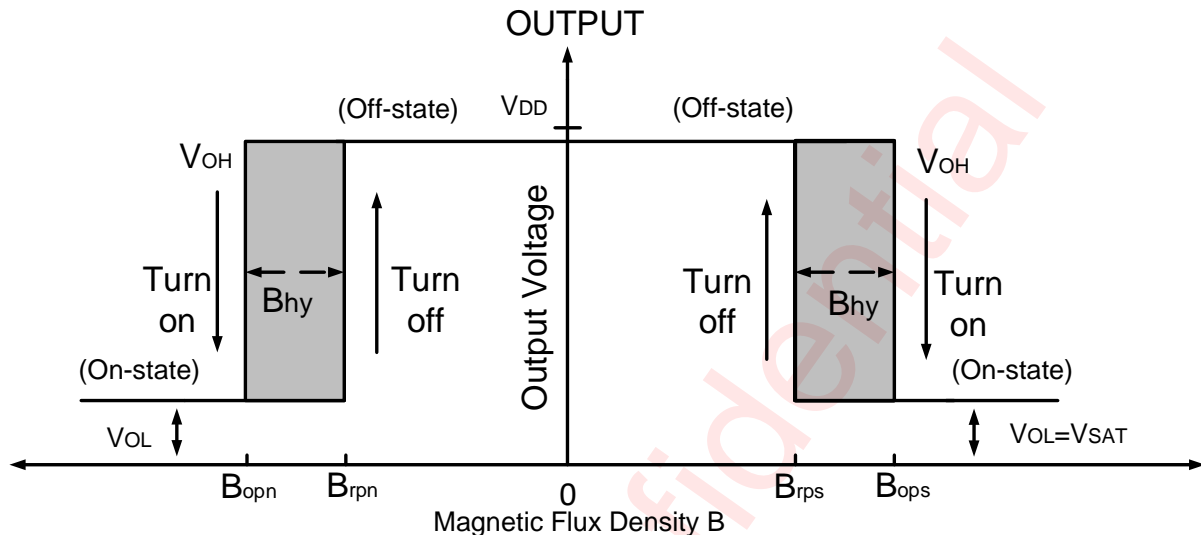


## Ordering Information

Part Number	Temperature	Package	Marking	Moisture Sensitivity Level	Environmental Information	Delivery Form
AW86515EBADNR	-40°C~85°C	WBDFN 1.6mm×1.2mm -4L	VNXD	MSL1	ROHS+HF	3000 units/ Tape and Reel

## Detailed Functional Description

When the magnetic field strength is greater than  $B_{opn}$ , then the device output is pulled low; When the magnetic field strength is less than  $B_{rpn}$ , then the device output is pulled high; When the magnetic field strength is between  $B_{opn}$  and  $B_{rpn}$ , then the device output remains in the previous state.



## Absolute Maximum Ratings

PARAMETERS	RANGE
Supply Voltage	6V
$V_{DD}$ Reverse Voltage $V_{DD}$	-0.3V
Supply Current	3mA
Output Voltage	-0.4V to $V_{DD}+0.4V$
Output Current	4mA
Operating Ambient Temperature $T_A$	-40°C to 85°C
Storage Temperature $T_{STG}$	-65°C to 150°C
Junction temperature $T_J$	-50°C to 165°C
Magnetic Flux	No limit
Package Power Dissipation	230mW
ESD Rating <sup>(NOTE2 3)</sup>	
Human Body Model (HBM) ESD capability	±6kV
Charged-device model (CDM) ESD capability	±1.5kV
Latch-up	
Test Condition: JESD78E	+ IT: 200mA - IT: 200mA

**NOTE1:** Conditions out of those ranges listed in "absolute maximum ratings" may cause permanent damages to the device. In spite of the limits above, functional operation conditions of the device should be within the ranges listed in "recommended operating conditions". Exposure to absolute-maximum-rated conditions for prolonged periods may affect device reliability.

**NOTE2:** The human body model is a 100pF capacitor discharged through a 1.5kΩ resistor into each pin. Test method: ESDA/JEDEC JS -001-2017.

**NOTE3:** Charge Device Model test method: ESDA/JEDEC JS-002-2018.

## Electrical Characteristics

$V_{DD}=3.3V$  supply,  $T_A=-40^{\circ}C$  to  $85^{\circ}C$  (unless otherwise noted)

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit
$V_{DD}$	Supply Voltage	Operating, $T_J < 165^{\circ}C$	1.6		5.5	V
$I_{DD}(\text{awake})$	Supply Current	During awake period, $T_A = 25^{\circ}C$ , $V_{DD}=3.3V$	-	0.95	1.3	mA
$I_{DD}(\text{sleep})$		During sleep period, $T_A = 25^{\circ}C$ , $V_{DD}=3.3V$	-	0.43	-	$\mu A$
$I_{DD}(\text{avg})$	Average supply current	$T_A = 25^{\circ}C$ , $V_{DD} = 1.8V$ , $f_S=20Hz$		0.8		$\mu A$
$V_{OL}$	Output low voltage(on)	$I_{OUT} = 1\text{ mA}$	-	0.1	0.2	V
$V_{OH}$	Output high voltage(off)	$I_{OUT} = -1mA$	$V_{DD}-0.2$	$V_{DD}-0.1$	-	V
$T_{\text{awake}}$	Awake time	(note)	-	40	60	$\mu s$
$T_{\text{period}}$	Period	$f_S=20Hz$ (sampling rate)		50	75	ms
D.C.	Duty cycle	-	-	0.08	-	%
$f_C$	Chopping Frequency		-	500	-	kHz
$I_{OFF}$	Output Leakage Current	$V_{OUT} = 5.5\text{ V}$ ; Switch state=off	-	-	0.1	$\mu A$

Note: Maximum and minimum parameters values over operating temperature range are not tested in production. They are guaranteed by design, characterization and process control. The magnetic field strength (Gauss) required to cause the switch to change state (operate and release) will be as specified in the magnetic characteristics. To test the switch against the specified magnetic characteristics, the switch must be placed in a uniform magnetic field.

## Magnetic Characteristics

$T_A=+25^{\circ}C$ ,  $V_{DD}=3.3V$  (unless otherwise noted)

(1 mT=10 Gauss)

Symbol	Characteristics	Test condition	Min	Typ	Max	Unit
Bops(south polar to part marking side)	Operation Point	$T_A=+25^{\circ}C$ , $V_{DD}=3.3V$	40	60	70	Gauss
Bopn(north pole to part marking side)		$T_A=+25^{\circ}C$ , $V_{DD}=3.3V$	-70	-60	-40	
Brps(sorth pole to part marking side)	Release Point	$T_A=+25^{\circ}C$ , $V_{DD}=3.3V$	38	50	65	
Brpn (north pole to part marking side)		$T_A=+25^{\circ}C$ , $V_{DD}=3.3V$	-65	-50	-38	
Bhy ( $ B_{opx} - B_{rpx} $ )	Hysteresis		-	10	-	

## Typical Characteristics

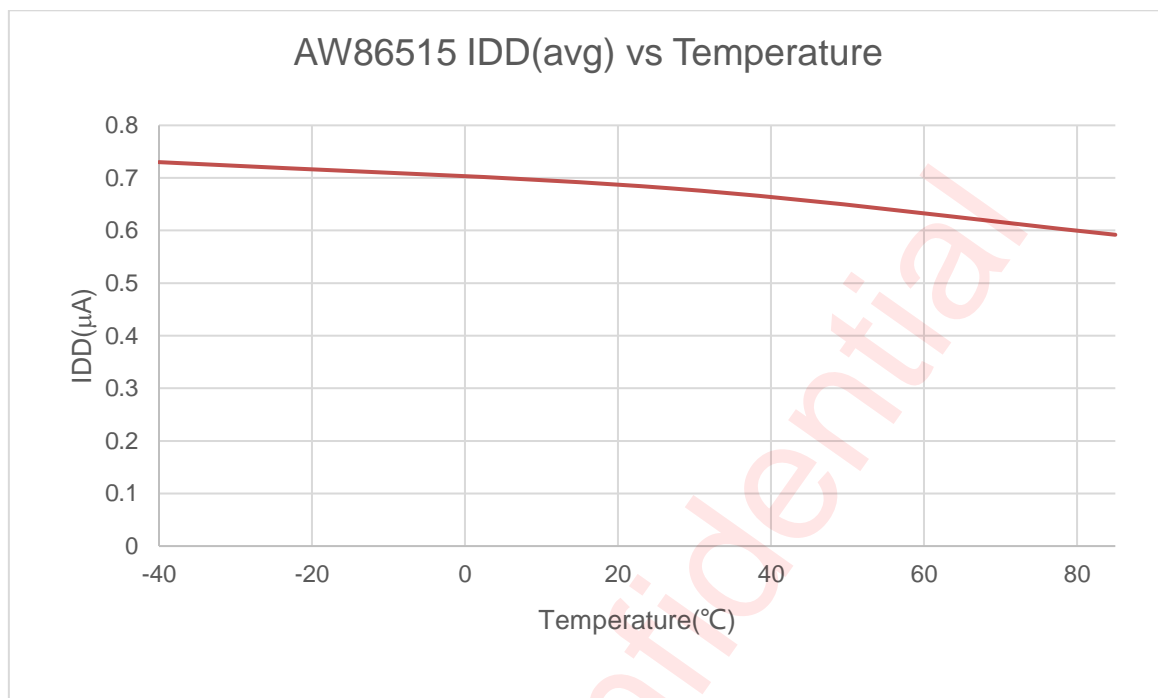


Figure 1 Ambient Temperature  $T_a$ [°C]  $I_{DD}$  vs.  $T_a$  (VDD=1.8V)

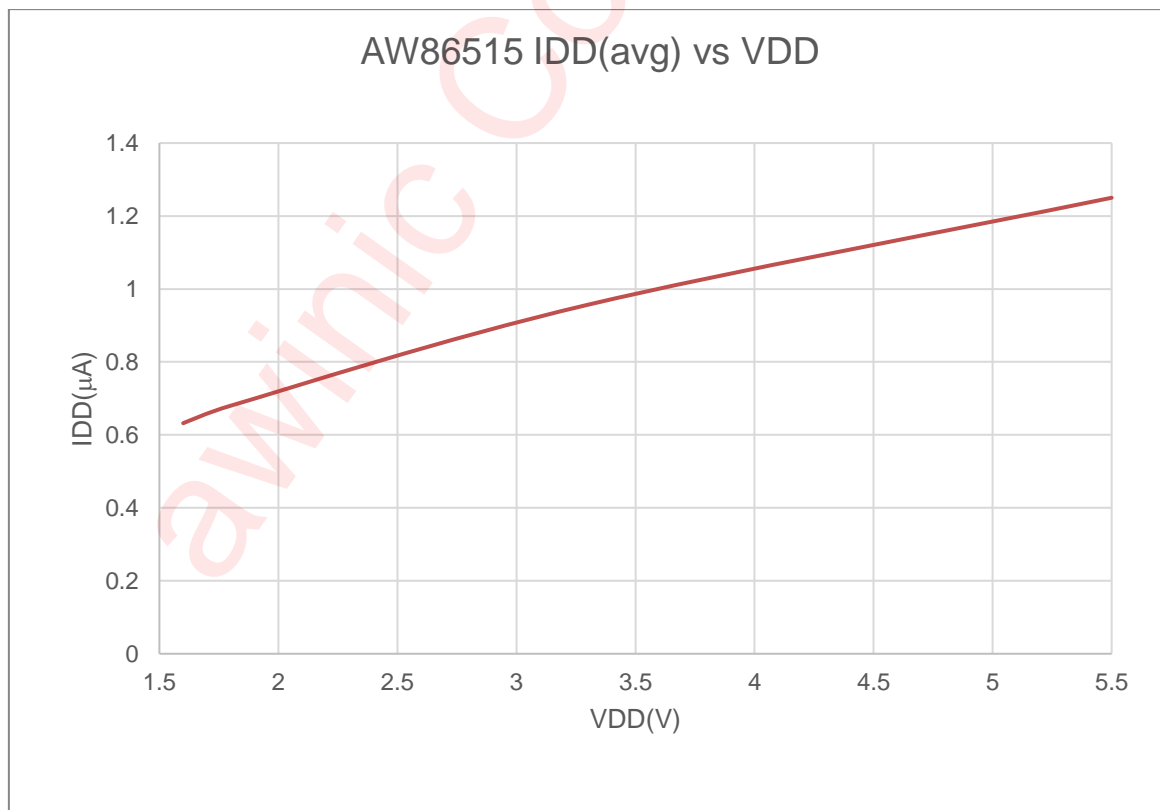


Figure 2 Average Supply Current vs. Supply Voltage( $T_a=25^{\circ}\text{C}$ )

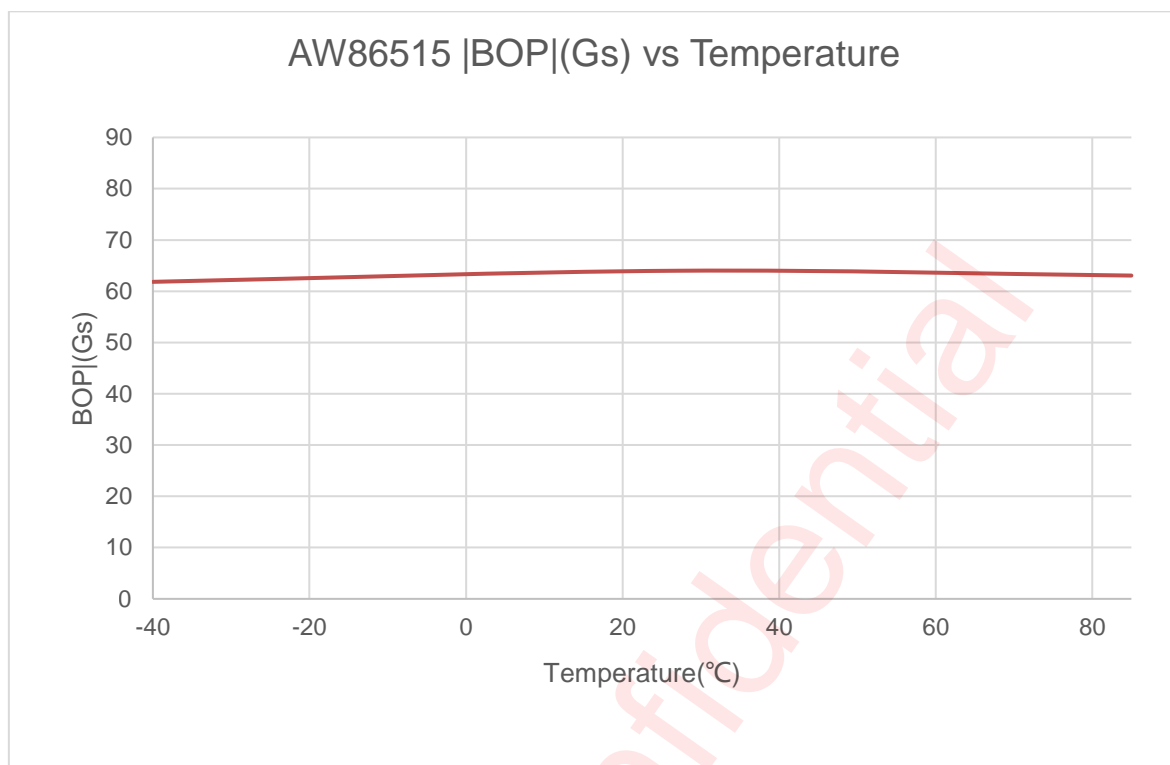


Figure 3 Ambient Temperature  $T_a$ [°C] |Bop| vs.  $T_a$ ( $V_{DD}=3.3V$ )

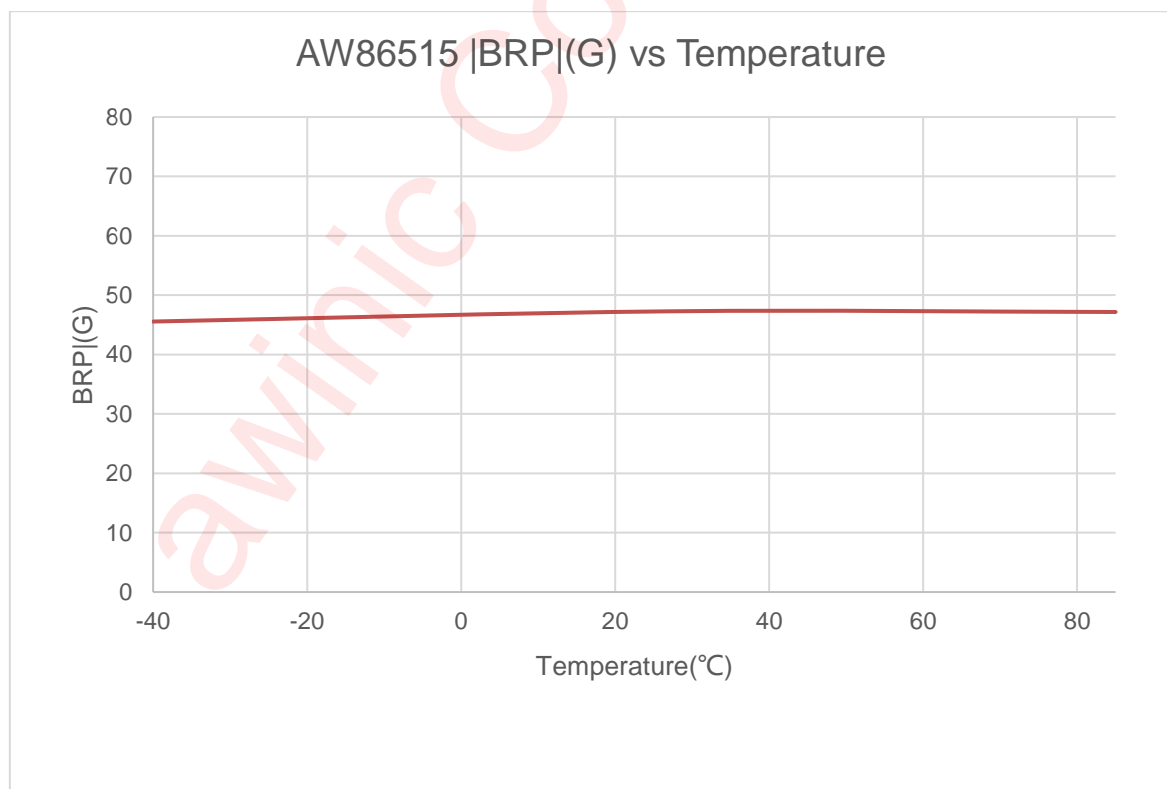


Figure 4 Ambient Temperature  $T_a$ [°C] |Brp| vs.  $T_a$ ( $V_{DD}=3.3V$ )

## Application Information

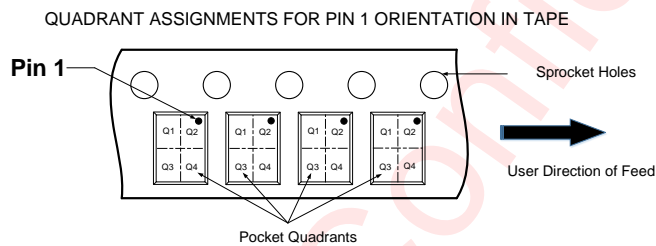
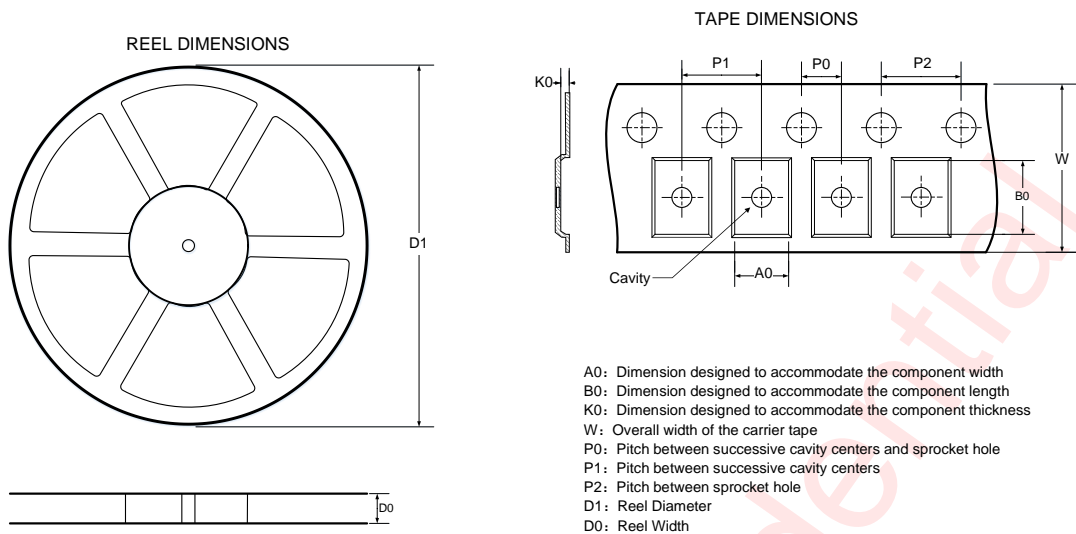
It is recommended to connect an external capacitor of  $0.1\mu\text{F}$  to VDD and GND. The noise of the injection device can be reduced.



Figure 5 The Application Circuit of AW86515EBADNR



## Tape And Reel Information



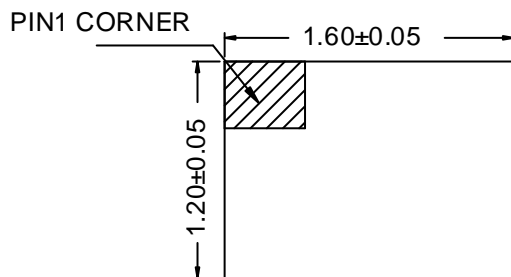
Note: The above picture is for reference only. Please refer to the value in the table below for the actual size

DIMENSIONS AND PIN1 ORIENTATION

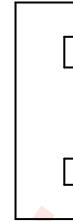
D1 (mm)	D0 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
178	8.4	1.37	1.77	0.55	2	4	4	8	Q2

All dimensions are nominal

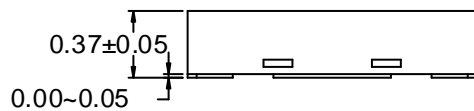
## Package Description



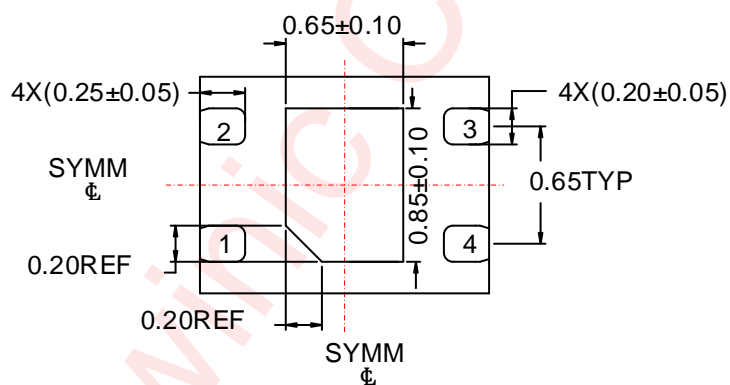
Top View



Side View



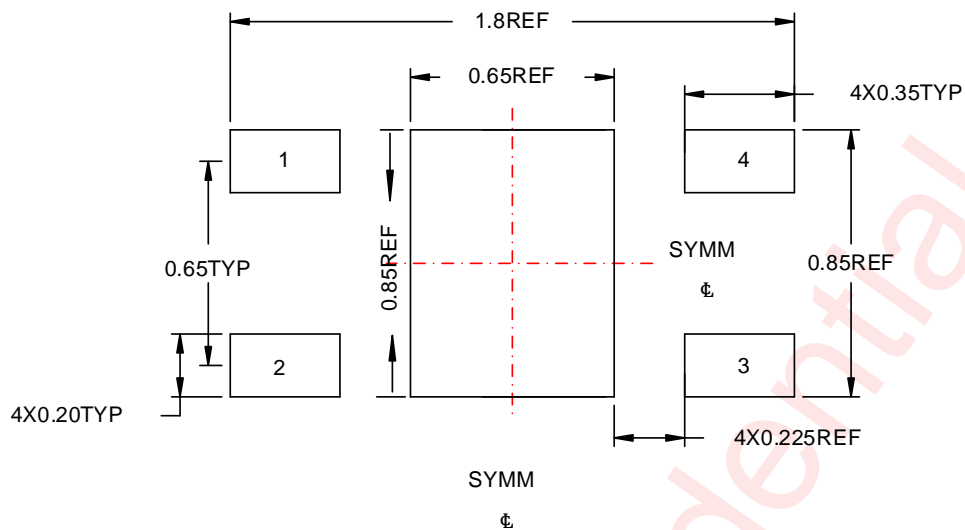
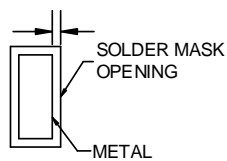
Side View



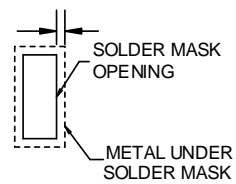
Bottom View

Unit: mm

## Land Pattern Data

0.05 MAX  
All AROUND

NON SOLDER MASK DEFINED

0.05 MIN  
All AROUND

SOLDER MASK DEFINED

Unit: mm

**REVISION HISTORY**

Version	Date	Change Record
V1.0	Sep. 2023	Officially released

awinic Confidential

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